

IL205A, IL206A, IL207A, IL208A,  
IL211A, IL212A, IL213A,



**SMALL OUTLINE OPTICALLY  
COUPLED ISOLATOR  
TRANSISTOR OUTPUT**

**DESCRIPTION**

This series of optically coupled isolators consist of a Gallium Arsenide infrared emitting diode and NPN silicon photo transistor mounted in a standard 8 pin SOIC package, which makes them ideally suited for high density applications with limited space.

**FEATURES**

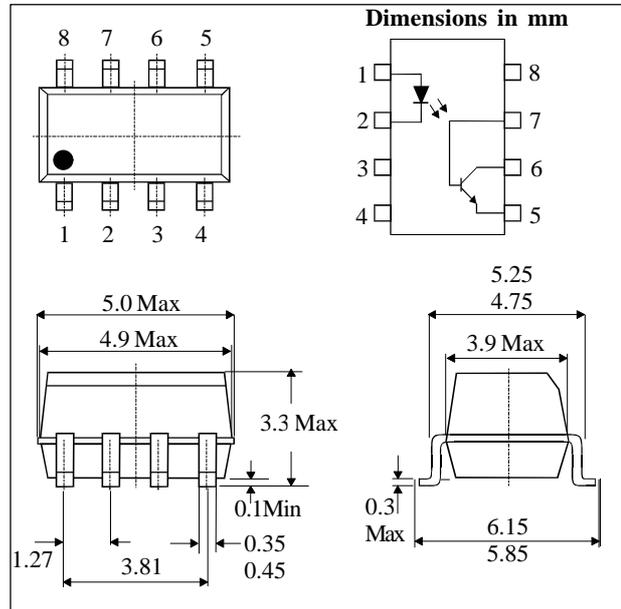
- Standard SOIC-8 Footprint with 0.05" Lead Spacing
- Specified min. and max. CTR at 10mA I<sub>F</sub>, 5V V<sub>CE</sub>  
IL205A, 40 - 80%  
IL206A, 63 - 125%  
IL207A, 100 - 200%  
IL208A, 160 - 320%
- Specified minimum CTR at 10mA I<sub>F</sub>, 5V V<sub>CE</sub>  
IL211A, 20%  
IL212A, 50%  
IL213A, 100%
- Specified minimum CTR at 1mA I<sub>F</sub>, 5V V<sub>CE</sub>  
IL215A, 20%  
IL216A, 50%  
IL217A, 100%
- Isolation Voltage, 2500 V<sub>RMS</sub>
- High BV<sub>CEO</sub> (70V min)
- All electrical parameters 100% tested
- Available in Tape and Reel - add suffix " T & R "
- Custom Electrical Selections available

**ABSOLUTE MAXIMUM RATINGS  
( 25°C unless otherwise noted)**

Storage Temperature \_\_\_\_\_ -55°C to +125°C  
Operating Temperature \_\_\_\_\_ -55°C to +100°C  
Lead Soldering Temperature \_\_\_\_\_ 260°C  
(single wave for 10 secs)  
Input to Output Isolation Voltage \_\_\_\_\_ 2500V<sub>RMS</sub>

**INPUT DIODE**

Forward D.C. Current \_\_\_\_\_ 60mA  
Reverse D.C. Voltage \_\_\_\_\_ 6V  
Peak Forward Current (tp ≤ 10µs) \_\_\_\_\_ 3A  
Power Dissipation \_\_\_\_\_ 100mW  
(derate linearly 1.33mW/°C above 25°C)  
Junction Temperature \_\_\_\_\_ 125°C



**APPLICATIONS**

- Computer Terminals
- Industrial Systems Controllers
- Hybrid substrates that require high density mounting
- Signal Transmission between systems of different potentials and impedances

**OUTPUT TRANSISTOR**

Collector-Emitter Voltage BV<sub>CEO</sub> \_\_\_\_\_ 70V  
Emitter-Collector Voltage BV<sub>ECO</sub> \_\_\_\_\_ 7V  
Collector -Base Voltage BV<sub>CBO</sub> \_\_\_\_\_ 70V  
Collector Current \_\_\_\_\_ 50mA  
Collector Current \_\_\_\_\_ 100mA  
(pw ≤ 10ms , 50% duty ratio)  
Power Dissipation \_\_\_\_\_ 150mW  
(derate linearly 2.00mW/°C above 25°C)  
Junction Temperature \_\_\_\_\_ 125°C

**PACKAGE**

Total Power Dissipation \_\_\_\_\_ 250mW  
(derate linearly 3.3mW/°C above 25°C)

**ISOCOM COMPONENTS LTD**

Unit 25B, Park View Road West,  
Park View Industrial Estate, Brenda Road  
Hartlepool, Cleveland, TS25 1YD  
Tel: (01429) 863609 Fax: (01429) 863581

**ISOCOM INC**

1024 S. Greenville Ave, Suite 240,  
Allen, TX 75002 USA  
Tel: (214) 495-0755 Fax: (214) 495-0901  
e-mail info@isocom.com  
http://www.isocom.com

**ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)**

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input	Forward Voltage ( $V_F$ ) Capacitance Reverse Current ( $I_R$ )		1.2 50	1.5 100	Volt pF $\mu$ A	$I_F = 10 \text{ mA}$ $V_R = 0, f = 1 \text{ MHz}$ $V_R = 6 \text{ V}$
Output	Collector-Emitter Voltage ( $BV_{CEO}$ ) Emitter-Collector Voltage ( $BV_{ECO}$ ) Collector-Base Voltage ( $BV_{CBO}$ ) Collector-Emitter Dark Current ( $I_{CEO}$ )	70 7 70			Volt Volt Volt nA	$I_C = 100 \mu\text{A}$ $I_E = 100 \mu\text{A}$ $I_C = 100 \mu\text{A}$ $V_{CE} = 10 \text{ V}$
Coupled	Current Transfer Ratio (CTR) IL205A	40		80	%	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$
	IL206A	63		125	%	
	IL207A	100		200	%	
	IL208A	160		320	%	
	IL211A	20			%	
	IL212A	50			%	
	IL213A	100			%	
	IL205A	13			%	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$
	IL206A	22			%	
	IL207A	34			%	
	IL208A	56			%	
	IL215A	20			%	
	IL216A	50			%	
	IL217A	100			%	
	Collector-Emitter Saturation Voltage $V_{CE(SAT)}$ (IL205A to IL213A)			0.4	Volt	$I_F = 10 \text{ mA}, I_C = 2 \text{ mA}$
	Collector-Emitter Saturation Voltage $V_{CE(SAT)}$ (IL215A to IL217A)			0.4	Volt	$I_F = 1 \text{ mA}, I_C = 0.1 \text{ mA}$
	Capacitance Input to Output ( $C_{IO}$ )		0.3		pF	$f = 1 \text{ MHz}$ (note 1)
	Input to Output Isolation Resistance ( $R_{IO}$ )	$10^{11}$			$\Omega$	$V_{IO} = 500 \text{ V}$ (note 1)
	Input to Output Isolation Voltage ( $V_{IO}$ )	2500			$V_{RMS}$	Note 1
	Output Turn on Time ( $t_{on}$ )		3.0		$\mu$ s	$I_C = 2 \text{ mA},$ $V_{CC} = 10 \text{ V}, R_L = 100 \Omega$
	Output Turn off Time ( $t_{off}$ )		3.0		$\mu$ s	
	Output Rise Time ( $t_r$ )		1.6		$\mu$ s	
	Output Fall Time ( $t_f$ )		2.2		$\mu$ s	

Note 1. Measured with input leads shorted together and output leads shorted together.

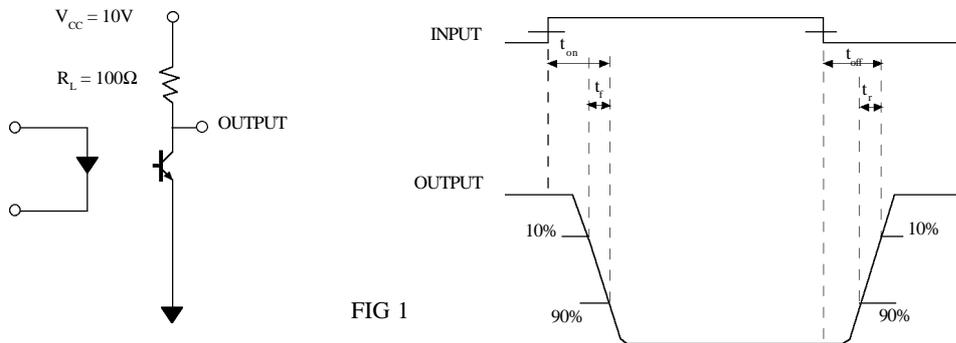
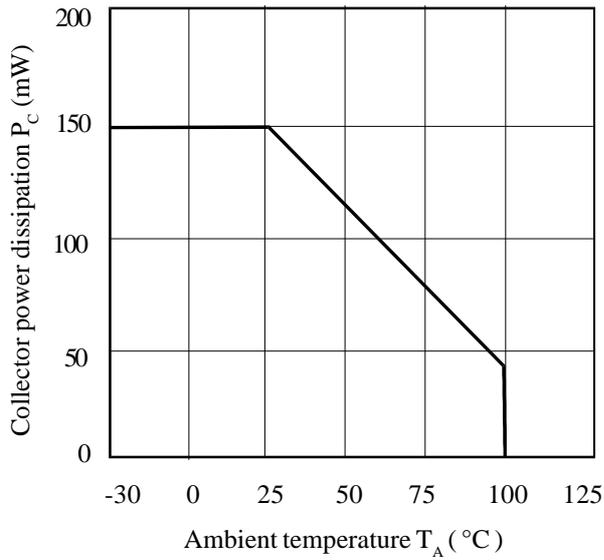
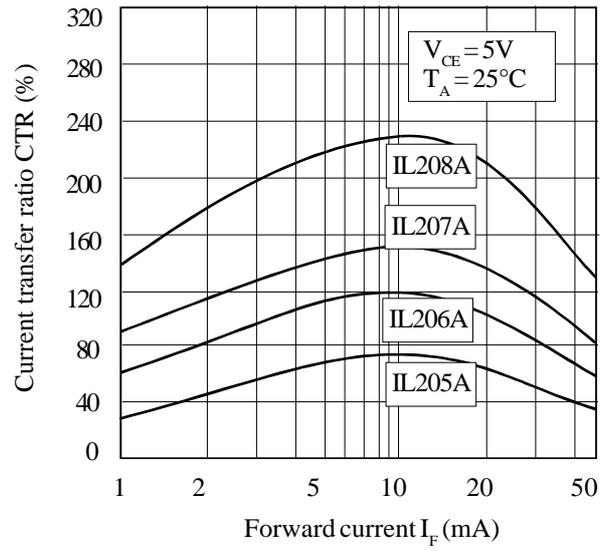


FIG 1

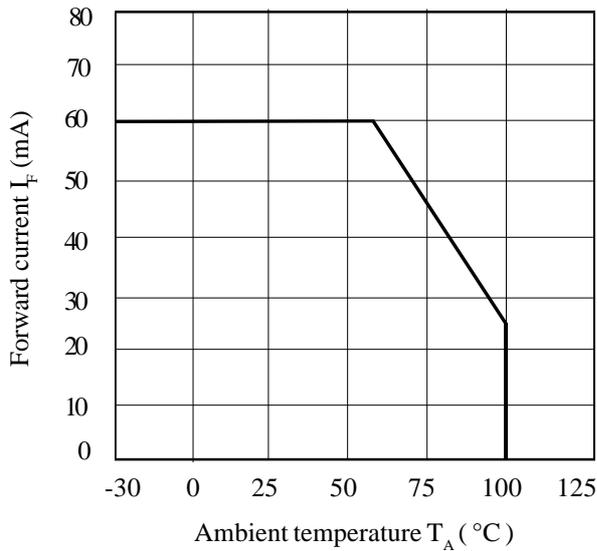
**Collector Power Dissipation vs. Ambient Temperature**



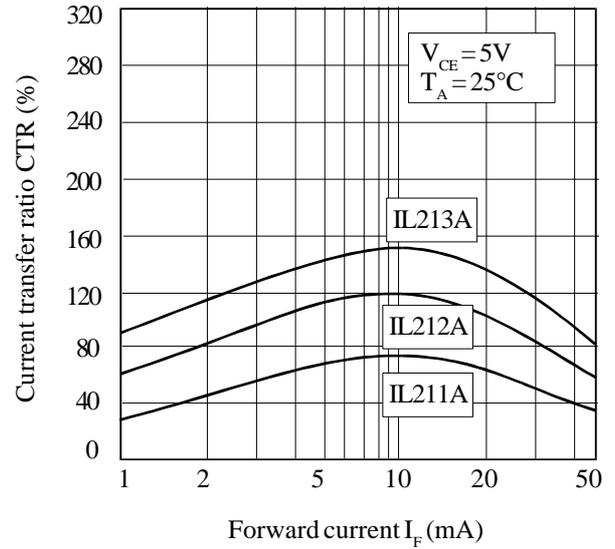
**Current Transfer Ratio vs. Forward Current**



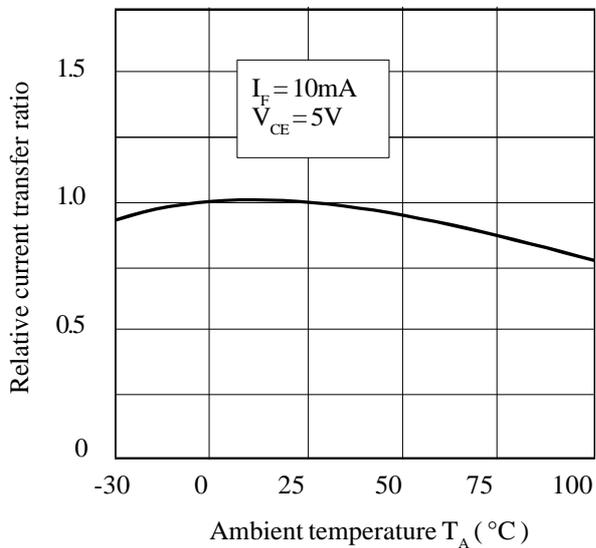
**Forward Current vs. Ambient Temperature**



**Current Transfer Ratio vs. Forward Current**



**Relative Current Transfer Ratio vs. Ambient Temperature**



**Current Transfer Ratio vs. Forward Current**

